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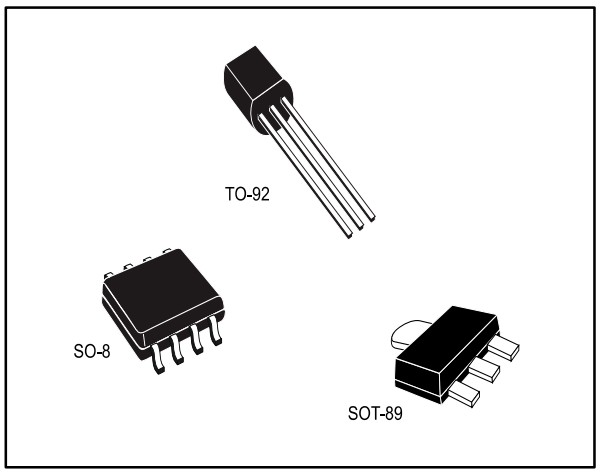
L78L

Positive voltage regulators

Datasheet - production data



Features

- Output current up to 100 mA
- Output voltages of 3.3; 5; 6; 8; 9; 10; 12; 15; 18; 24 V thermal overload protection
- Short-circuit protection
- No external components are required
- Available in either ± 4% (A) or ± 8% (C) selection

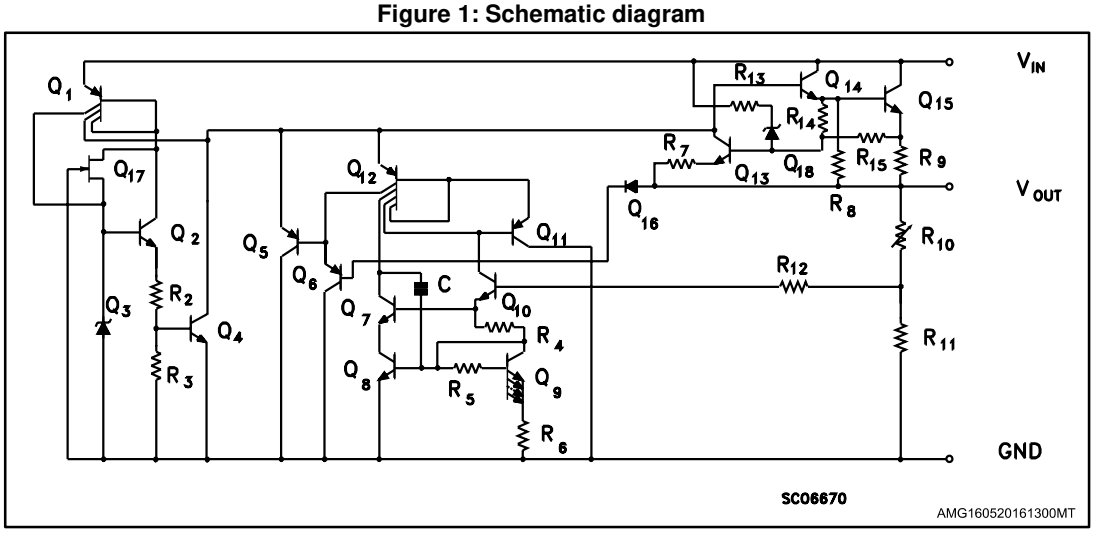
Description

The L78L series of three-terminal positive regulators employ internal current limiting and thermal shutdown, making them essentially indestructible. If adequate heat-sink is provided, they can deliver up to 100 mA output current. They are intended as fixed voltage regulators in a wide range of applications including local or on-card regulation for elimination of noise and distribution problems associated with single-point regulation. In addition, they can be used with power pass elements to make high-current voltage regulators. The L78L series used as Zener diode/resistor combination replacement, offers e improvement along with lower quiescent current and lower noise.

Contents

1 Diagram

Figure 1: Schematic diagram



2 Pin configuration

Figure 2: Pin connection (top view, bottom view for TO-92)

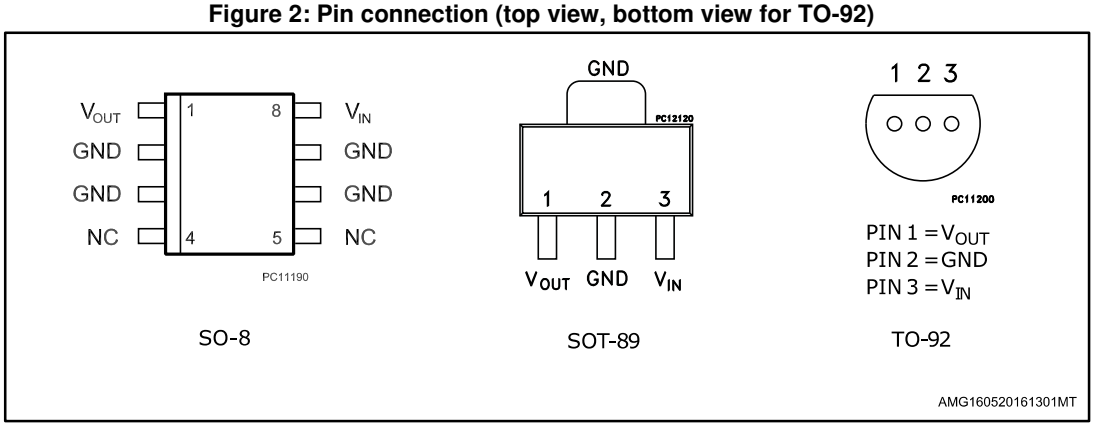
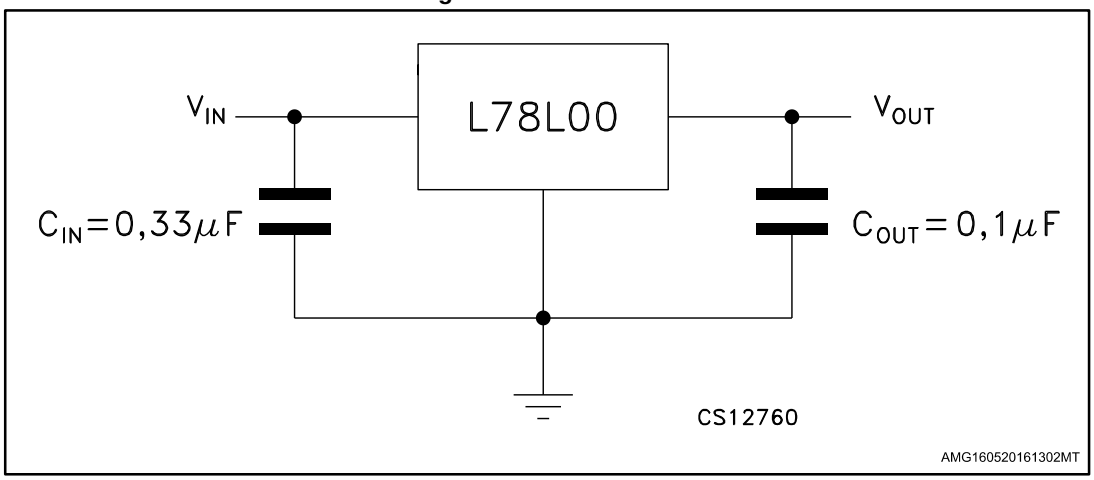


Figure 3: Test circuits



3 Maximum ratings

Table 1: Absolute maximum ratings

Symbol	Parameter		Value	Unit
V_I	DC Input voltage	V_O = 3.3 to 9 V	30	V
		V_O = 12 to 15 V	35	
		V_O = 18 to 24 V	40	
I_O	Output current		100	mA
P_D	Power dissipation		Internally limited (1)	mW
T_{STG}	Storage temperature range		-65 to 150	°C
T_{OP}	Operating junction temperature range	for L78LxxAC / L78LxxC	0 to 125	°C
		for L78LxxAB	-40 to 125	

Notes:

(1)Our SO-8 package used for voltage regulators is modified internally to have pins 2, 3, 6 and 7 electrically communed to the die attach flag. This particular frame decreases the total thermal resistance of the package and increases its ability to dissipate power when an appropriate area of copper on the printed circuit board is available for heat-sinking. The external dimensions are the same as for the standard SO-8.

Table 2: Thermal data

Symbol	Parameter	SO-8	TO-92	SOT-89	Unit
R_{thJC}	Thermal resistance junction-case (max)	20		15	°C/W
R_{thJA}	Thermal resistance junction-ambient (max)	55 (1)	200	55 (1)	°C/W

Notes:

(1)Considering 6 cm² of copper Board heat-sink.

4 Electrical characteristics

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 8.3 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 3: Electrical characteristics of L78L33C

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	3.036	3.3	3.564	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 5.3 to 20 V	2.97		3.63	V
		I_O = 1 to 70 mA, V_I = 8.3 V	2.97		3.63	
ΔV_O	Line regulation	V_I = 5.4 to 20 V, T_J = 25 °C			150	mV
		V_I = 6.3 to 20 V, T_J = 25 °C			100	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			60	mV
		I_O = 1 to 40 mA, T_J = 25 °C			30	
I_d	Quiescent current	T_J = 25 °C			6	mA
		T_J = 125 °C			5.5	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.2	mA
		V_I = 6.3 to 20 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		40		µV
SVR	Supply voltage rejection	V_I = 6.3 to 16.3 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	41	49		dB
V_d	Dropout voltage			2		V

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 10 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 4: Electrical characteristics of L78L05C

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	4.6	5	5.4	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 7 to 20 V	4.5		5.5	V
		I_O = 1 to 70 mA, V_I = 10 V	4.5		5.5	
ΔV_O	Line regulation	V_I = 8.5 to 20 V, T_J = 25 °C			200	mV
		V_I = 9 to 20 V, T_J = 25 °C			150	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			60	mV
		I_O = 1 to 40 mA, T_J = 25 °C			30	
I_d	Quiescent current	T_J = 25 °C			6	mA
		T_J = 125 °C			5.5	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.2	mA
		V_I = 8 to 20 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		40		µV
SVR	Supply voltage rejection	V_I = 9 to 20 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	40	49		dB
V_d	Dropout voltage			2		V

Refer to the test circuits, T_J = 0 to 125 °C,V_I = 14 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 5: Electrical characteristics of L78L08C

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	7.36	8	8.64	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 8.5 to 20 V	7.2		8.8	V
		I_O = 1 to 70 mA, V_I = 12 V	7.2		8.8	
ΔV_O	Line regulation	V_I = 10.5 to 20 V, T_J = 25 °C			200	mV
		V_I = 11 to 20 V, T_J = 25 °C			150	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			80	mV
		I_O = 1 to 40 mA, T_J = 25 °C			40	
I_d	Quiescent current	T_J = 25 °C			6	mA
		T_J = 125 °C			5.5	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.2	mA
		V_I = 8 to 20 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		60		µV
SVR	Supply voltage rejection	V_I = 9 to 20 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	36	45		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 15 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 6: Electrical characteristics of L78L09C

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	8.28	9	9.72	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 11.5 to 23 V	8.1		9.9	V
		I_O = 1 to 70 mA, V_I = 15 V	8.1		9.9	
ΔV_O	Line regulation	V_I = 11.5 to 23 V, T_J = 25 °C			250	mV
		V_I = 12 to 23 V, T_J = 25 °C			200	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			80	mV
		I_O = 1 to 40 mA, T_J = 25 °C			40	
I_d	Quiescent current	T_J = 25 °C			6	mA
		T_J = 125 °C			5.5	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.2	mA
		V_I = 12 to 23 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		70		µV
SVR	Supply voltage rejection	V_I = 12 to 23 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	36	44		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 16 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 7: Electrical characteristics of L78L10C

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	9.2	10	10.8	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 12.5 to 23 V	9		11	V
		I_O = 1 to 70 mA, V_I = 16 V	9		11	
ΔV_O	Line regulation	V_I = 12.5 to 23 V, T_J = 25 °C			230	mV
		V_I = 13 to 23 V, T_J = 25 °C			170	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			80	mV
		I_O = 1 to 40 mA, T_J = 25 °C			40	
I_d	Quiescent current	T_J = 25 °C			6	mA
		T_J = 125 °C			5.5	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.1	mA
		V_I = 13 to 23 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		60		µV
SVR	Supply voltage rejection	V_I = 14 to 23 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	37	45		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 19 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 8: Electrical characteristics of L78L12C

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	11.1	12	12.9	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 14.5 to 27 V	10.8		13.2	V
		I_O = 1 to 70 mA, V_I = 19 V	10.8		13.2	
ΔV_O	Line regulation	V_I = 14.5 to 27 V, T_J = 25 °C			250	mV
		V_I = 16 to 27 V, T_J = 25 °C			200	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			100	mV
		I_O = 1 to 40 mA, T_J = 25 °C			50	
I_d	Quiescent current	T_J = 25 °C			6.5	mA
		T_J = 125 °C			6	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.2	mA
		V_I = 16 to 27 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		80		µV
SVR	Supply voltage rejection	V_I = 15 to 25 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	36	42		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 23 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified

Table 9: Electrical characteristics of L78L15C

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	13.8	15	16.2	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 17.5 to 30 V	13.5		16.5	V
		I_O = 1 to 70 mA, V_I = 23 V	13.5		16.5	
ΔV_O	Line regulation	V_I = 17.5 to 30 V, T_J = 25 °C			300	mV
		V_I = 20 to 30 V, T_J = 25 °C			250	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			150	mV
		I_O = 1 to 40 mA, T_J = 25 °C			75	
I_d	Quiescent current	T_J = 25 °C			6.5	mA
		T_J = 125 °C			6	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.2	mA
		V_I = 20 to 30 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		90		µV
SVR	Supply voltage rejection	V_I = 18.5 to 28.5 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	33	39		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 27 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 10: Electrical characteristics of L78L18C

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	16.6	18	19.4	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 22 to 33 V	16.2		19.8	V
		I_O = 1 to 70 mA, V_I = 27 V	16.2		19.8	
ΔV_O	Line regulation	V_I = 22 to 33 V, T_J = 25 °C			320	mV
		V_I = 22 to 33 V, T_J = 25 °C			270	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			170	mV
		I_O = 1 to 40 mA, T_J = 25 °C			85	
I_d	Quiescent current	T_J = 25 °C			6.5	mA
		T_J = 125 °C			6	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.2	mA
		V_I = 23 to 33 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		120		µV
SVR	Supply voltage rejection	V_I = 23 to 33 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	32	38		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C, V_I = 33 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 11: Electrical characteristics of L78L24C

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	22.1	24	25.9	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 27 to 38 V	21.6		26.4	V
		I_O = 1 to 70 mA, V_I = 33 V	21.6		26.4	
ΔV_O	Line regulation	V_I = 27 to 38 V, T_J = 25 °C			350	mV
		V_I = 28 to 38 V, T_J = 25 °C			300	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			200	mV
		I_O = 1 to 40 mA, T_J = 25 °C			100	
I_d	Quiescent current	T_J = 25 °C			6.5	mA
		T_J = 125 °C			6	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.2	mA
		V_I = 28 to 38 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		200		µV
SVR	Supply voltage rejection	V_I = 29 to 35 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	30	37		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C (AC) T_J = -40 to 125 °C (AB),V_I = 8.3 V, I_O = 40mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 12: Electrical characteristics of L78L33AB and L78L33AC

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	3.168	3.3	3.432	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 5.3 to 20 V	3.135		3.465	V
		I_O = 1 to 70 mA, V_I = 8.3 V	3.135		3.465	
ΔV_O	Line regulation	V_I = 5.4 to 20 V, T_J = 25 °C			150	mV
		V_I = 6.3 to 20 V, T_J = 25 °C			100	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			60	mV
		I_O = 1 to 40 mA, T_J = 25 °C			30	
I_d	Quiescent current	T_J = 25 °C			6	mA
		T_J = 125 °C			5.5	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.1	mA
		V_I = 6.3 to 20 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		40		µV
SVR	Supply voltage rejection	V_I = 6.3 to 16.3 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	41	49		dB
V_d	Dropout voltage			2		V

Refer to the test circuits, T_J = 0 to 125 °C (AC) T_J = -40 to 125 °C (AB), V_I = 10 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 13: Electrical characteristics of L78L05AB and L78L05AC

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	4.8	5	5.2	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 7 to 20 V	4.75		5.25	V
		I_O = 1 to 70 mA, V_I = 10 V	4.75		5.25	
ΔV_O	Line regulation	V_I = 7.3 to 20 V, T_J = 25 °C			150	mV
		V_I = 8 to 20 V, T_J = 25 °C			100	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			60	mV
		I_O = 1 to 40 mA, T_J = 25 °C			30	
I_d	Quiescent current	T_J = 25 °C			6	mA
		T_J = 125 °C			5.5	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.1	mA
		V_I = 8 to 20 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		40		µV
SVR	Supply voltage rejection	V_I = 8 to 18 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	41	49		dB
V_d	Dropout voltage			2		V

Refer to the test circuits, T_J = 0 to 125 °C (AC) T_J = -40 to 125 °C (AB), V_I = 12 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 14: Electrical characteristics of L78L06AB and L78L06AC

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	5.76	6	6.24	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 8.5 to 20 V	5.7		6.3	V
		I_O = 1 to 70 mA, V_I = 12 V	5.7		6.3	
ΔV_O	Line regulation	V_I = 8.5 to 20 V, T_J = 25 °C			150	mV
		V_I = 9 to 20 V, T_J = 25 °C			100	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			60	mV
		I_O = 1 to 40 mA, T_J = 25 °C			30	
I_d	Quiescent current	T_J = 25 °C			6	mA
		T_J = 125 °C			5.5	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.1	mA
		V_I = 9 to 20 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		50		µV
SVR	Supply voltage rejection	V_I = 9 to 20 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	39	46		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C (AC) T_J = -40 to 125 °C (AB), V_I = 14 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 15: Electrical characteristics of L78L08AB and L78L08AC

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	7.68	8	8.32	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 10.5 to 23 V	7.6		8.4	V
		I_O = 1 to 70 mA, V_I = 14 V	7.6		8.4	
ΔV_O	Line regulation	V_I = 10.5 to 23 V, T_J = 25 °C			175	mV
		V_I = 11 to 23 V, T_J = 25 °C			125	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			80	mV
		I_O = 1 to 40 mA, T_J = 25 °C			40	
I_d	Quiescent current	T_J = 25 °C			6	mA
		T_J = 125 °C			5.5	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.1	mA
		V_I = 11 to 23 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		60		µV
SVR	Supply voltage rejection	V_I = 12 to 23 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	37	45		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C (AC) T_J = -40 to 125 °C (AB), V_I =15 V, I_O= 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 16: Electrical characteristics of L78L09AB and L78L09AC

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	8.64	9	9.36	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 11.5 to 23 V	8.55		9.45	V
		I_O = 1 to 70 mA, V_I = 15 V	8.55		9.45	
ΔV_O	Line regulation	V_I = 11.5 to 23 V, T_J = 25 °C			225	mV
		V_I = 12 to 23 V, T_J = 25 °C			150	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			80	mV
		I_O = 1 to 40 mA, T_J = 25 °C			40	
I_d	Quiescent current	T_J = 25 °C			6	mA
		T_J = 125 °C			5.5	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.1	mA
		V_I = 12 to 23 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		70		µV
SVR	Supply voltage rejection	V_I = 12 to 23 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	37	44		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C (AC) T_J = -40 to 125 °C (AB), V_I= 16 V, I_O = 40mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 17: Electrical characteristics of L78L10AC

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	9.6	10	10.4	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 12.5 to 23 V	9.5		10.5	V
		I_O = 1 to 70 mA, V_I = 16 V	9.5		10.5	
ΔV_O	Line regulation	V_I = 12.5 to 23 V, T_J = 25 °C			230	mV
		V_I = 13 to 23 V, T_J = 25 °C			170	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			80	mV
		I_O = 1 to 40 mA, T_J = 25 °C			40	
I_d	Quiescent current	T_J = 25 °C			6	mA
		T_J = 125 °C			5.5	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.1	mA
		V_I = 13 to 23 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		60		µV
SVR	Supply voltage rejection	V_I = 14 to 23 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	37	45		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C (AC) T_J = -40 to 125 °C (AB), V_I =19 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 18: Electrical characteristics of L78L12AB and L78L12AC

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	11.5	12	12.5	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 14.5 to 27 V	11.4		12.6	V
		I_O = 1 to 70 mA, V_I = 19 V	11.4		12.6	
ΔV_O	Line regulation	V_I = 14.5 to 27 V, T_J = 25 °C			250	mV
		V_I = 16 to 27 V, T_J = 25 °C			200	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			100	mV
		I_O = 1 to 40 mA, T_J = 25 °C			50	
I_d	Quiescent current	T_J = 25 °C			6.5	mA
		T_J = 125 °C			6	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.1	mA
		V_I = 16 to 27 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		80		µV
SVR	Supply voltage rejection	V_I = 15 to 25 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	37	42		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C (AC) T_J = -40 to 125 °C (AB),V_I = 23 V, I_O= 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 19: Electrical characteristics of L78L15AB and L78L15AC

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	14.4	15	15.6	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 17.5 to 30 V	14.25		15.75	V
		I_O = 1 to 70 mA, V_I = 23 V	14.25		15.75	
ΔV_O	Line regulation	V_I = 17.5 to 30 V, T_J = 25 °C			300	mV
		V_I = 20 to 30 V, T_J = 25 °C			250	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			150	mV
		I_O = 1 to 40 mA, T_J = 25 °C			75	
I_d	Quiescent current	T_J = 25 °C			6.5	mA
		T_J = 125 °C			6	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.1	mA
		V_I = 20 to 30 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		90		µV
SVR	Supply voltage rejection	V_I = 18.5 to 28.5 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	34	39		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C (AC) T_J = -40 to 125 °C (AB),V_I = 27 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 20: Electrical characteristics of L78L18AC

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	17.3	18	18.7	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 22 to 33 V	17.1		18.9	V
		I_O = 1 to 70 mA, V_I = 27 V	17.1		18.9	
ΔV_O	Line regulation	V_I = 22 to 33 V, T_J = 25 °C			320	mV
		V_I = 22 to 33 V, T_J = 25 °C			270	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			170	mV
		I_O = 1 to 40 mA, T_J = 25 °C			85	
I_d	Quiescent current	T_J = 25 °C			6.5	mA
		T_J = 125 °C			6	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.1	mA
		V_I = 23 to 33 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		120		µV
SVR	Supply voltage rejection	V_I = 23 to 33 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	33	38		dB
V_d	Dropout voltage			1.7		V

Refer to the test circuits, T_J = 0 to 125 °C (AC) T_J = -40 to 125 °C (AB),V_I = 33 V, I_O = 40 mA, C_I = 0.33 µF, C_O = 0.1 µF unless otherwise specified.

Table 21: Electrical characteristics of L78L24AB and L78L24AC

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	T_J = 25 °C	23	24	25	V
V_O	Output voltage	I_O = 1 to 40 mA, V_I = 27 to 38 V	22.8		25.2	V
		I_O = 1 to 70 mA, V_I = 33 V	22.8		25.2	
ΔV_O	Line regulation	V_I = 27 to 38 V, T_J = 25 °C			350	mV
		V_I = 28 to 38 V, T_J = 25 °C			300	
ΔV_O	Load regulation	I_O = 1 to 100 mA, T_J = 25 °C			200	mV
		I_O = 1 to 40 mA, T_J = 25 °C			100	
I_d	Quiescent current	T_J = 25 °C			6.5	mA
		T_J = 125 °C			6	mA
ΔI_d	Quiescent current change	I_O = 1 to 40 mA			0.1	mA
		V_I = 28 to 38 V			1.5	
eN	Output noise voltage	B = 10 Hz to 100 kHz, T_J = 25 °C		200		µV5y
SVR	Supply voltage rejection	V_I = 29 to 33 V, f = 120 Hz I_O = 40 mA, T_J = 25 °C	31	37		dB
V_d	Dropout voltage			1.7		V

5 Typical performance

Figure 4: L78L05/12 output voltage vs. ambient temperature

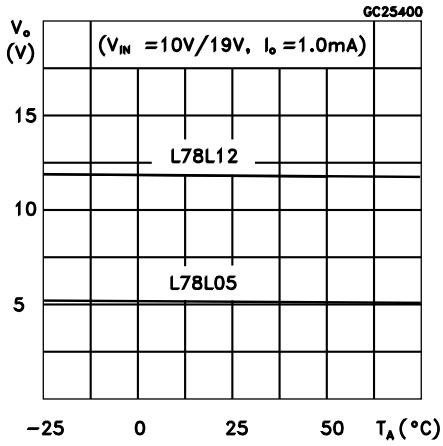


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Figure 5: L78L05/12/24 load characteristics

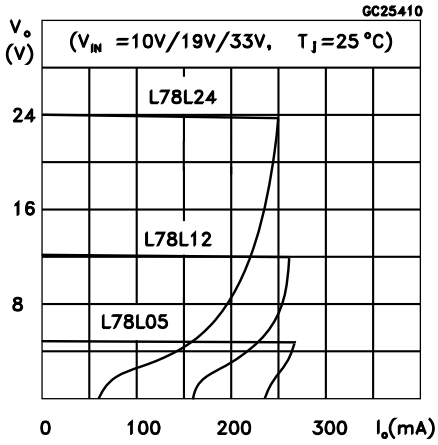

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Figure 6: L78L05/12/24 thermal shutdown

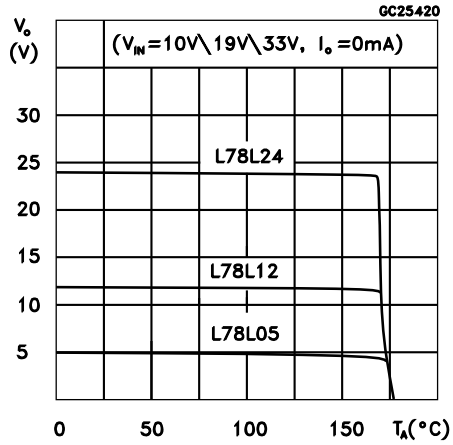

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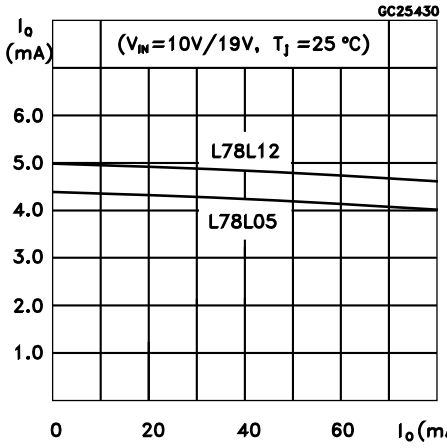
Figure 7: L78L05/12 quiescent current vs. output current



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